(1) E-mail on July 10, 2018 from Yoshi to Albert (2) E-mail on July 10, 2018 from Albert to Yoshi Private Communications with Prof. Albert Theuwissen > FROM: hagiwara [mailto:hagiwara-yoshiaki@aiplab.com] >From: albert theuwissen >Sent: Tuesday, July 10, 2018 6:55 PM on the invention of Pinned Photo Diode (PPD) > SENT: Tuesday, July 10, 2018 3:19 PM >To: hagiwara-yoshiaki@aiplab.com >Subject: (1) E-mail on July 10, 2018 from Yoshi to Albert > TO: 'a.theuwissen' >Re: How are you ? from Yoshi of Sony(Hagiwara180710) > SUBJECT: RE: NEC-SONY Patent War >Dear Yoshi. (2) E-mail on July 10, 2018 from Albert to Yoshi > Hi, Albert, >Good to hear from you, although it is not all good news >you are sending to me. > how are you? Peter Noble invented in 1966 the in-pixel active >Can you tell me the reference of the Pain paper? (\*) > I am very mad at Fossum's 2014 paper > which I found just a few weeks ago. >When and where was it published? source-follower type current amplifier circuit. > I am now 70 years and completely retired.. >Very interesting information!! Peter Nobel, IEEE Transaction of Electron Devices 15-4 (1968) pp. 202-209. > Fossum did not quote the very important >At the time Fossum started to write the overview paper >about the PPD, he asked me to become a co-author > Pain's work at JPL CalTech on the active photo sensor with the built-in source-follower type >and to help him out with the paper. >on the Global Shutter CMOS image sensor ... > Yoshi >After some doubt I declined his invitation, in-pixel current amplifier circuit, a very important element >because I do know that the discussion On Tue, 10 Jul 2018 18:24:23 +0900, hagiwara wrote: >about the inventor of the PPD is very sensitive. for modern CMOS image sensors. > Albert, >and I do agree with you that the structure >vou developed is indeed a PPD. > I am sorry my previous e-mail title was in Japanese, >maybe not called that way at that time and (2) Yoshiaki Hagiwara invented the Pinned Photo Diode > copying to many unrelated people. >also invented for some other purpose. with the vertical OFD (VOD). > But they are also my friends. >But it still remains a PPD! The combination of the Pinned Photodiode (JPA1975-127646 and JPA1975-127647 > I am re-sending with more information >At Philips, in the late '70s a very similar structure > on the Pain's paper. (\*) >was implemented in the CCDs, this was before >I joined Philips in 1983. with the pinned surface with the VOD (JPA1975-134985) and the no-image-lag > You know, I was also a visiting professor > at Caltech during 1998 to 1999 >So yes, there were several p+/n-/p- structures feature automatically realizes the completely mechanical-parts free >known by the time that Teranishi issued his patent. > and frequently visiting Pain's Lab at JPL, Electric Shutter function and its clocking scheme (JPA1977-126885). > Caltech during the period. >I fully agree to that. >Looking forward to hear from you, > I remember Pain and his team really hated >Regards, > Fossum at that time. >Albert. (3) Fossum (CMOS image sensor) and Teranish (CCD image sensor) are incorrectly > I recall they called Fossum a thief. (\*) Guang Yang, Orly Yadid-Pecht, Chris Wrigley, and Bedabrata Pain, attributed to the CCD and CMOS invention and development efforts. " A Snap-Shot CMOS Active Pixel Imager for Low-Noise, High-speed Imaging", > Kind regards IEDM1998, Digest of Technical Papers, paper (2.7), (1998). > Yoshi